

isc N-Channel MOSFET Transistor
IRFB3207ZG, IIRFB3207ZG
• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 4.1m\Omega$
- Enhancement mode
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

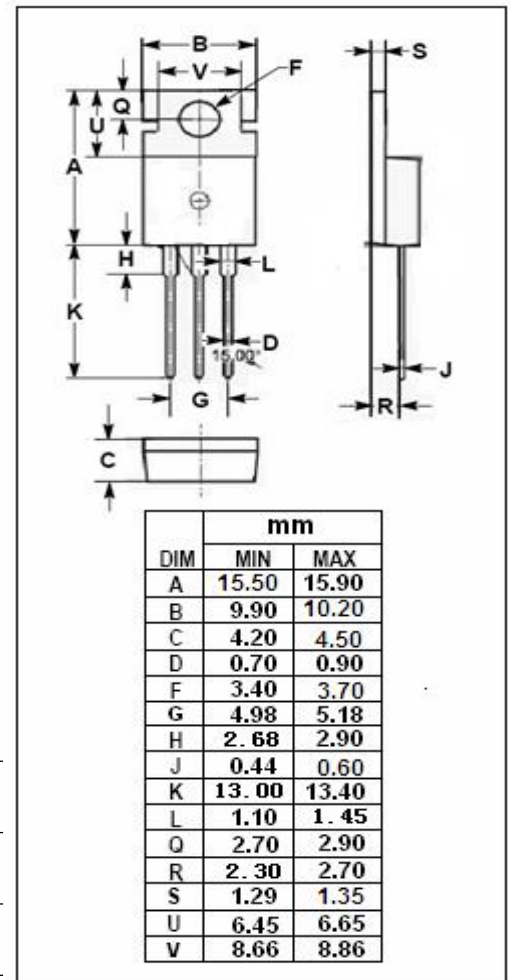
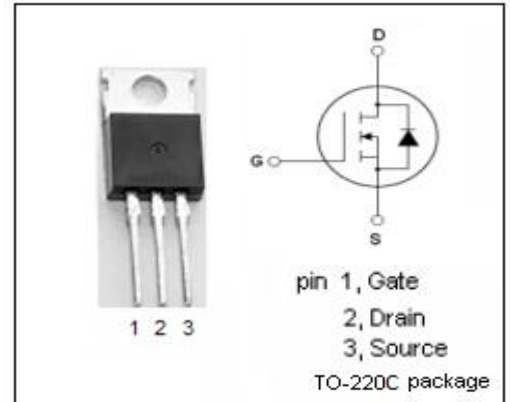
- reliable device for use in a wide variety of applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	75	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	120	A
I_{DM}	Drain Current-Single Pulsed	670	A
P_D	Total Dissipation @ $T_c=25^\circ C$	300	W
T_j	Max. Operating Junction Temperature	175	$^\circ C$
T_{stg}	Storage Temperature	-55~175	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.5	$^\circ C/W$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62	$^\circ C/W$



isc N-Channel MOSFET Transistor**IRFB3207ZG, IIRFB3207ZG****ELECTRICAL CHARACTERISTICS** $T_C=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V; I_D=250\ \mu\text{A}$	75			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}; I_D=150\ \mu\text{A}$	2		4	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V; I_D=75A$			4.1	$m\ \Omega$
I_{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm 20V$			± 0.1	μA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=75V; V_{GS}=0V$			20	μA
V_{SD}	Diode forward voltage	$I_S=75A, V_{GS}=0V$			1.3	V

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